TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

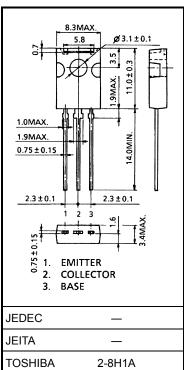
2SA1356

Audio Power Amplifier Applications

- Low saturation voltage: V_{CE} (sat) = -0.32 V (typ.) (I_C = -500 mA, I_B = -50 mA)
- High collector power dissipation: $P_C = 1.2 \text{ W} (Ta = 25^{\circ}C)$
- Complementary to 2SC3419

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-40	V	
Collector-emitter voltage		V _{CEO}	-40	V	
Emitter-base voltage		V _{EBO}	-5	V	
Collector current		Ι _C	-800	mA	
Base current		Ι _Β	-80	mA	
Collector power dissipation	Ta = 25°C	Pc	1.2	W	
	Tc = 25°C	FC	5		
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

Weight: 0.82 g (typ.)

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

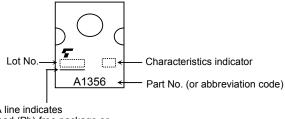
Unit: mm

Electrical Characteristics (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -40 \text{ V}, \text{ I}_{E} = 0$	_	_	-1.0	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 V, I_C = 0$	_	_	-1.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0	-40	—		V
DC current gain	h _{FE (1)} (Note)	V _{CE} = -2 V, I _C = -50 mA	70		240	
	h _{FE (2)}	$V_{CE} = -2 V, I_C = -800 mA$	13	50	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -500 mA, I _B = -50 mA	_	-0.32	-0.8	V
Base-emitter voltage	V _{BE}	$V_{CE} = -2 V, I_C = -500 mA$	_	_	-1.3	V
Transition frequency	f _T	V _{CE} = -2 V, I _C = -0.5 A	50	100	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz		20		pF

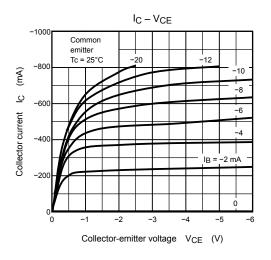
Note: h_{FE (1)} classification O: 70 to 140, Y: 120 to 240

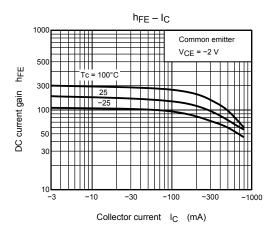
Marking

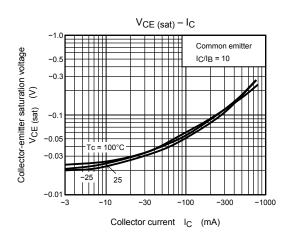


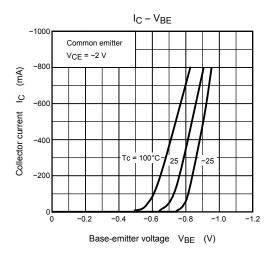
A line indicates lead (Pb)-free package or lead (Pb)-free finish.

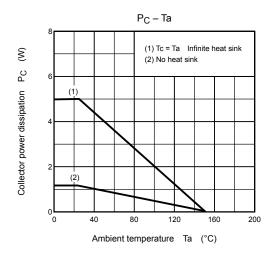
TOSHIBA



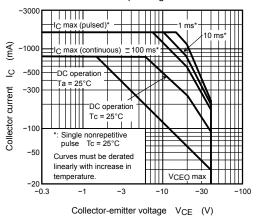








Safe Operating Area



RESTRICTIONS ON PRODUCT USE

20070701-EN

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